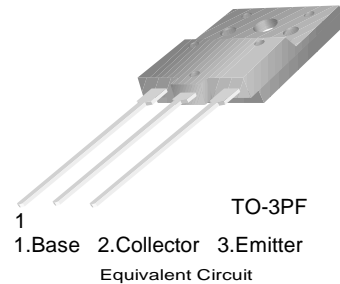


FJAF6806D

FJAF6806D

High Voltage Color Display Horizontal Deflection Output (Damper Diode Built In)

- High Collector-Base Breakdown Voltage : $BV_{CBO} = 1500V$
- High Switching Speed : $t_f(\text{typ.}) = 0.1\mu s$
- For Color TV



NPN Triple Diffused Planar Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

| Symbol | Parameter | Rating | Units |
|------------|---------------------------|-----------|------------|
| V_{CBO} | Collector-Base Voltage | 1500 | V |
| V_{CEO} | Collector-Emitter Voltage | 750 | V |
| V_{EBO} | Emitter-Base Voltage | 6 | V |
| I_C | Collector Current (DC) | 6 | A |
| I_{CP}^* | Collector Current (Pulse) | 12 | A |
| P_C | Collector Dissipation | 50 | W |
| T_J | Junction Temperature | 150 | $^\circ C$ |
| T_{STG} | Storage Temperature | -55 ~ 150 | $^\circ C$ |

* Pulse Test: Pulse Width=5ms, Duty Cycle $\leq 10\%$

Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|------------------------|--------------------------------------|--|--------|-----|-----|---------|
| I_{CES} | Collector Cut-off Current | $V_{CB}=1400V, R_{BE}=0$ | | | 1 | mA |
| I_{CBO} | Collector Cut-off Current | $V_{CB}=800V, I_E=0$ | | | 10 | μA |
| I_{EBO} | Emitter Cut-off Current | $V_{EB}=4V, I_C=0$ | 40 | | 200 | mA |
| BV_{EBO} | Base-Emitter Breakdown Voltage | $I_E=300mA, I_C=0$ | 6 | | | V |
| h_{FE1} h_{FE2} | DC Current Gain | $V_{CE}=5V, I_C=1A$ $V_{CE}=5V, I_C=4A$ | 8 4 | | 7 | |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C=4A, I_B=1A$ | | | 5 | V |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C=4A, I_B=1A$ | | | 1.5 | V |
| V_F | Damper Diode Turn On Voltage | $I_F = 4.5A$ | | | 2 | V |
| t_{STG}^* | Storage Time | $V_{CC}=200V, I_C=4A, R_L=50\Omega$ | | | 3 | μs |
| t_F^* | Fall Time | $I_{B1}=1.0A, I_{B2}= - 2.0A$ | | | 0.2 | μs |

* Pulse Test: $PW=20\mu s$, duty Cycle=1% Pulsed

Thermal Characteristics $T_C=25^\circ C$ unless otherwise noted

| Symbol | Parameter | Typ | Max | Units |
|-----------------|--------------------------------------|-----|-----|--------------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | | 2.5 | $^\circ C/W$ |

Typical Characteristics

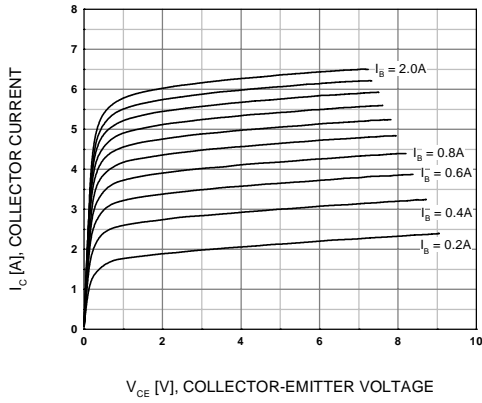


Figure 1. Static Characteristic

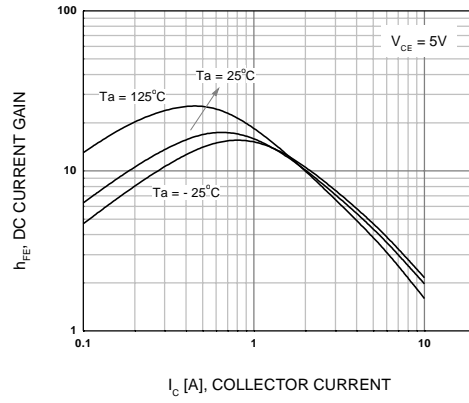


Figure 2. DC current Gain

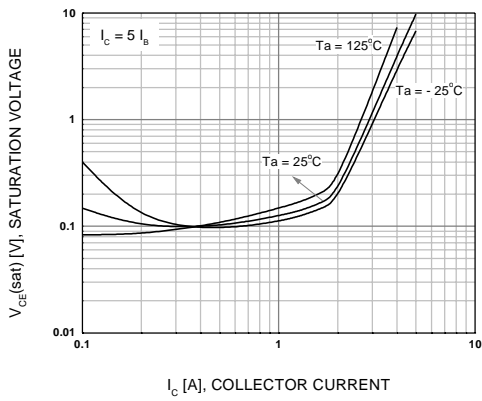


Figure 3. Collector-Emitter Saturation Voltage

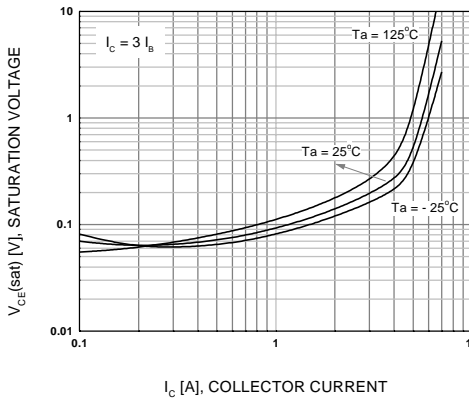


Figure 4. Collector-Emitter Saturation Voltage

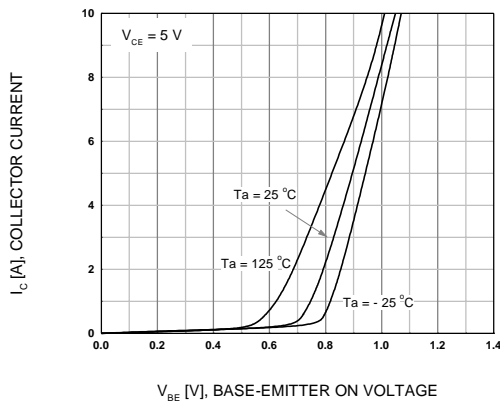


Figure 5. Base-Emitter On Voltage

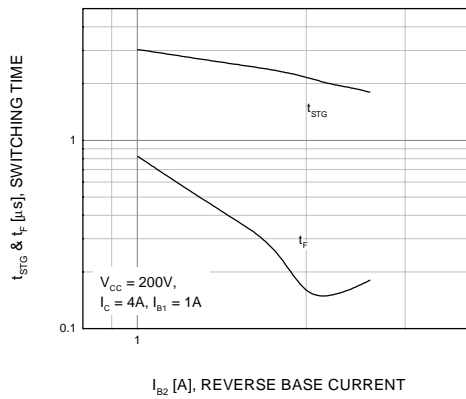


Figure 6. Resistive Load Switching Time

Typical Characteristics (Continued)

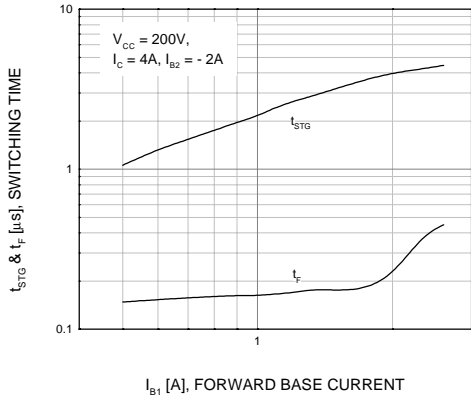


Figure 7. Resistive Load Switching Time

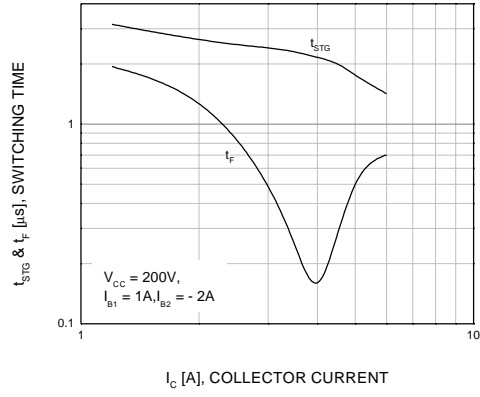


Figure 8. Resistive Load Switching Time

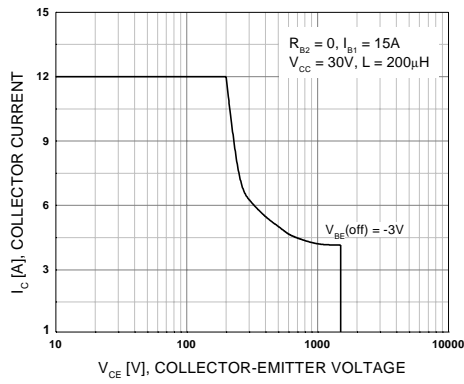


Figure 9. Reverse Bias Safe Operating Area

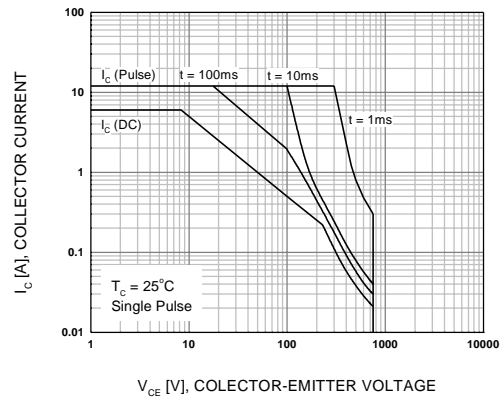


Figure 10. Forward Bias Safe Operating Area

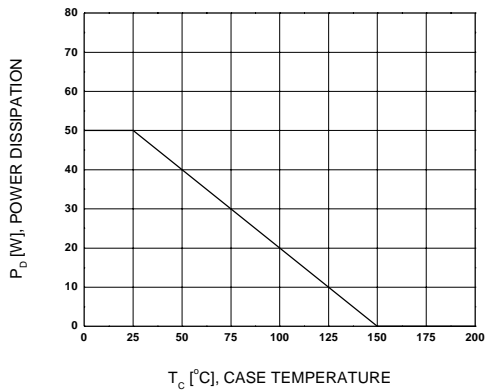


Figure 11. Power Derating

Package Dimensions

FJAF6806D

TO-3PF



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

| | | | | |
|----------------------|---------------------|---------------------|-----------------|------|
| ACE ^x ™ | FAST ^r ™ | OPTOLOGIC® | SMART START™ | VCX™ |
| Bottomless™ | FRFET™ | OPTOPLANAR™ | SPM™ | |
| CoolFET™ | GlobalOptoisolator™ | PACMAN™ | Stealth™ | |
| CROSSVOLT™ | GTO™ | POP™ | SuperSOT™-3 | |
| DOME™ | HiSeC™ | Power247™ | SuperSOT™-6 | |
| EcoSPARK™ | I ² C™ | PowerTrench® | SuperSOT™-8 | |
| E ² CMOS™ | ISOPLANAR™ | QFET™ | SyncFET™ | |
| EnSigna™ | LittleFET™ | QS™ | TinyLogic™ | |
| FACT™ | MicroFET™ | QT Optoelectronics™ | TruTranslation™ | |
| FACT Quiet series™ | MicroPak™ | Quiet Series™ | UHC™ | |
| FAST® | MICROWIRE™ | SLIENT SWITCHER® | UltraFET® | |

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition |
|--------------------------|------------------------|---|
| Advance Information | Formative or In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. |
| Preliminary | First Production | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| No Identification Needed | Full Production | This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| Obsolete | Not In Production | This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only. |



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.